

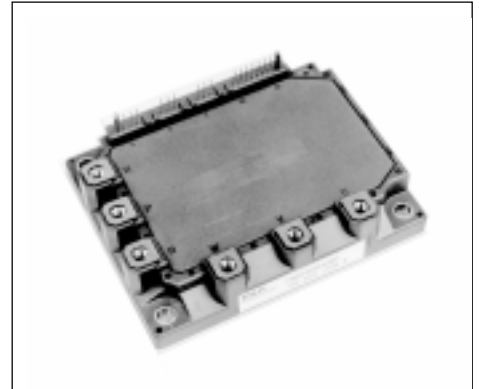
6MBP75RA120

IGBT-IPM R series

1200V / 75A 6 in one-package

Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- Compatible with existing IPM-N series packages
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



Maximum ratings and characteristics

- Absolute maximum ratings(at $T_c=25^\circ\text{C}$ unless otherwise specified)

Item	Symbol	Rating		Unit		
		Min.	Max.			
DC bus voltage	V_{DC}	0	900	V		
DC bus voltage (surge)	$V_{DC(surge)}$	0	1000	V		
DC bus voltage (short operating)	V_{SC}	200	800	V		
Collector-Emitter voltage	V_{CES}	0	1200	V		
INV	Collector current	DC	I_C	-	75	A
		1ms	I_{CP}	-	150	A
		DC	$-I_C$	-	75	A
	Collector power dissipation	One transistor	P_C	-	500	W
Junction temperature	T_J	-	150	$^\circ\text{C}$		
Input voltage of power supply for Pre-Driver	V_{CC}^*1	0	20	V		
Input signal voltage	V_{in}^*2	0	V_z	V		
Input signal current	I_{in}	-	1	mA		
Alarm signal voltage	V_{ALM}^*3	0	V_{CC}	V		
Alarm signal current	I_{ALM}^*4	-	15	mA		
Storage temperature	T_{stg}	-40	125	$^\circ\text{C}$		
Operating case temperature	T_{op}	-20	100	$^\circ\text{C}$		
Isolating voltage (Case-Terminal)	V_{iso}^*5	-	AC2.5	kV		
Screw torque	Mounting (M5)	-	3.5 *6	N·m		
	Terminal (M5)	-	3.5 *6	N·m		

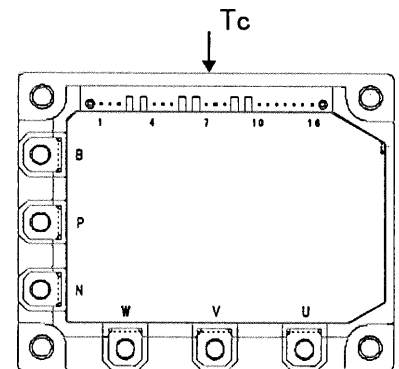


Fig.1 Measurement of case temperature

*1 Apply V_{CC} between terminal No. 3 and 1, 6 and 4, 9 and 7, 11 and 10.

*2 Apply V_{in} between terminal No. 2 and 1, 5 and 4, 8 and 7, 13,14,15 and 10.

*3 Apply V_{ALM} between terminal No. 16 and 10.

*4 Apply I_{ALM} to terminal No. 16.

*5 50Hz/60Hz sine wave 1 minute.

*6 Recommendable Value : 2.5 to 3.0 N·m

Electrical characteristics of power circuit (at $T_c=T_J=25^\circ\text{C}$, $V_{CC}=15\text{V}$)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit	
INV	Collector current at off signal input	I_{CES}	$V_{CE}=1200\text{V}$ input terminal open	-	-	1.0	mA
	Collector-Emitter saturation voltage	$V_{CE(sat)}$	$I_C=75\text{A}$	-	-	2.6	V
	Forward voltage of FWD	V_F	$-I_C=75\text{A}$	-	-	3.0	V

● Electrical characteristics of control circuit(at Tc=Tj=25°C, Vcc=15V)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Power supply current of P-line side Pre-driver(one unit)	I _{ccp}	fsw=0 to 15kHz Tc=-20 to 100°C *7	3	-	18	mA
Power supply current of N-line side three Pre-driver	I _{ccn}	fsw=0 to 15kHz Tc=-20 to 100°C *7	10	-	65	mA
Input signal threshold voltage (on/off)	V _{in(th)}	ON	1.00	1.35	1.70	V
		OFF	1.25	1.60	1.95	V
Input zener voltage	V _Z	R _{in} =20k ohm	-	8.0	-	V
Over heating protection temperature level	T _{COH}	VDC=0V, I _c =0A, Case temperature	110	-	125	°C
Hysteresis	T _{CH}		-	20	-	°C
IGBT chips over heating protection temperature level	T _{JOH}	surface of IGBT chips	150	-	-	°C
Hysteresis	T _{JH}		-	20	-	°C
Collector current protection level	INV	I _{oc}	T _j =125°C	113	-	A
Over current protection delay time (Fig.2)	t _{DOC}	T _j =25°C Fig.2	-	10	-	μs
Under voltage protection level	V _{UV}		11.0	-	12.5	V
Hysteresis	V _H		0.2	-	-	V
Alarm signal hold time	t _{ALM}		1.5	2	-	ms
SC protection delay time	t _{SC}	T _j =25°C Fig.3	-	-	12	μs
Limiting resistor for alarm	R _{ALM}		1425	1500	1575	ohm

*7 Switching frequency of IGBT

● Dynamic characteristics(at Tc=Tj=125°C, Vcc=15V)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Switching time (IGBT)	ton	I _C =75A, VDC=600V	0.3	-	-	μs
	toff					
Switching time (FWD)	t _{rr}	I _F =75A, VDC=600V	-	-	0.4	μs

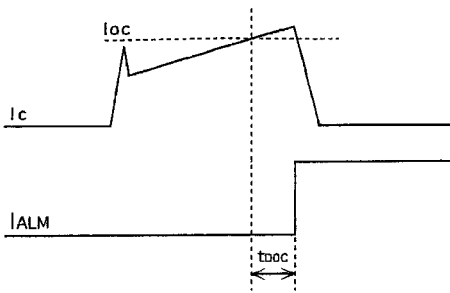


Fig.2 Definition of OC delay time

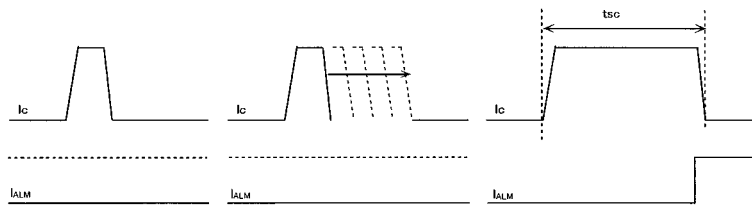


Fig.3 Definition of tsc

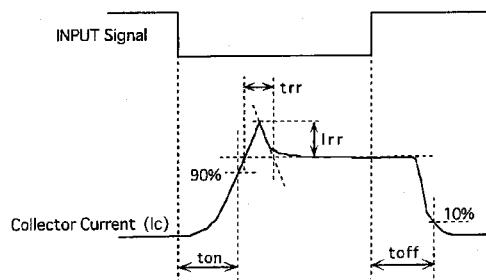


Fig.4 Definition of switching time

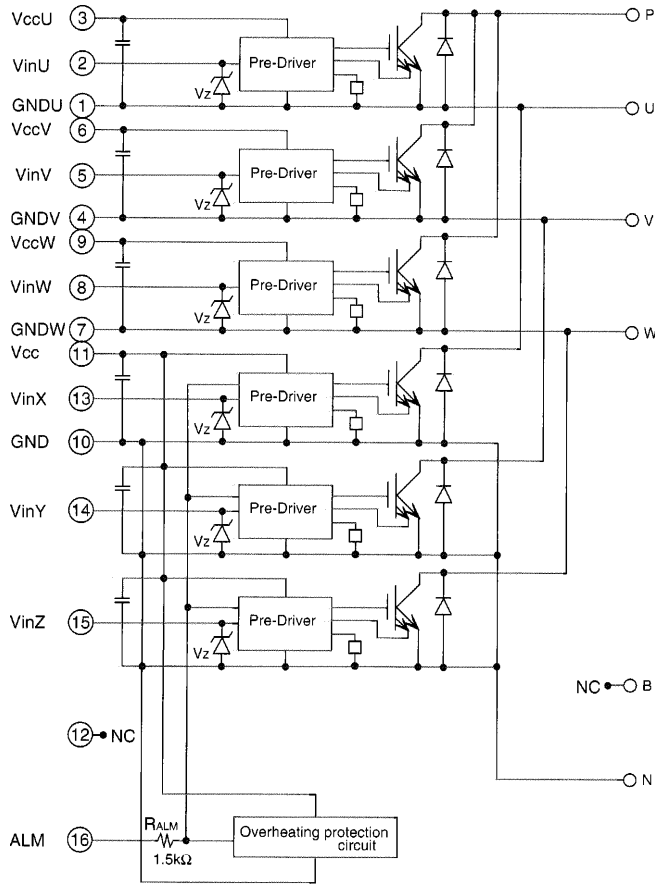
● Thermal characteristics(Tc=25°C)

Item	Symbol	Typ.	Max.	Unit		
Junction to Case thermal resistance	INV	IGBT	R _{th(j-c)}	-	0.25	°C/W
		FWD	R _{th(j-c)}	-	0.73	°C/W
Case to fin thermal resistance with compound	R _{th(c-f)}	0.05	-	°C/W		

● Recommendable value

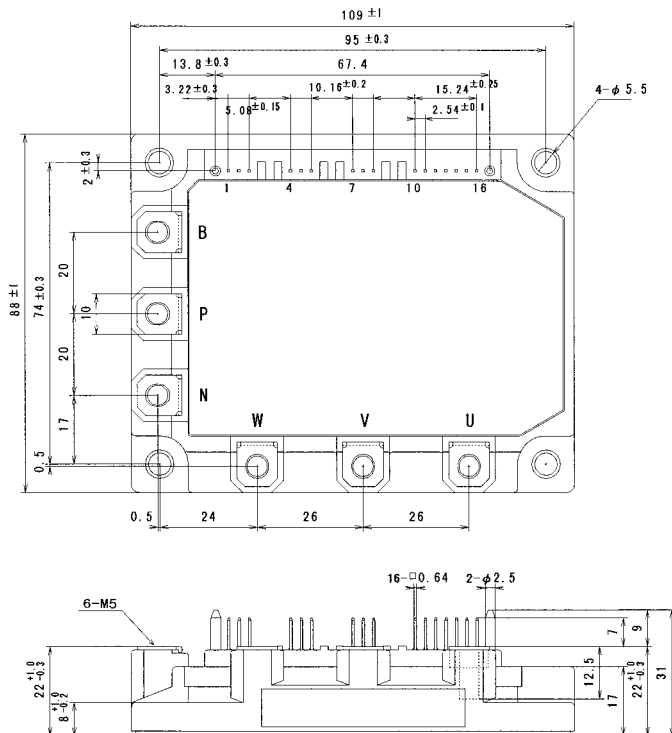
Item	Symbol	Min.	Typ.	Max.	Unit	
DC bus voltage	V _{DC}	200	-	800	V	
Operating power supply voltage range of Pre-driver	V _{CC}	13.5	15	16.5	V	
Switching frequency of IPM	fsw	1	-	20	kHz	
Screw torque	Mounting (M5)	-	2.5	-	3.0	N·m
	Terminal (M5)	-	2.5	-	3.0	N·m

Block diagram



- Pre-drivers include following functions
- a) Amplifier for driver
 - b) Short circuit protection
 - c) Undervoltage lockout circuit
 - d) Over current protection
 - e) IGBT chip over heating protection

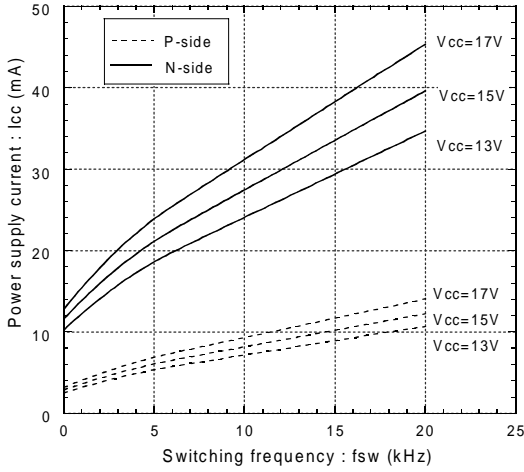
Outline drawings, mm



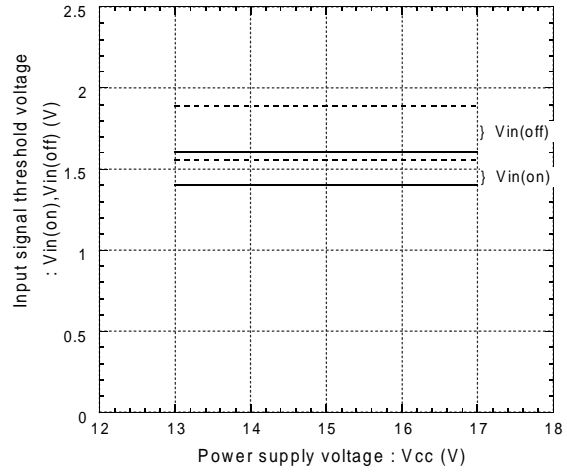
Characteristics (Representative)

Control Circuit

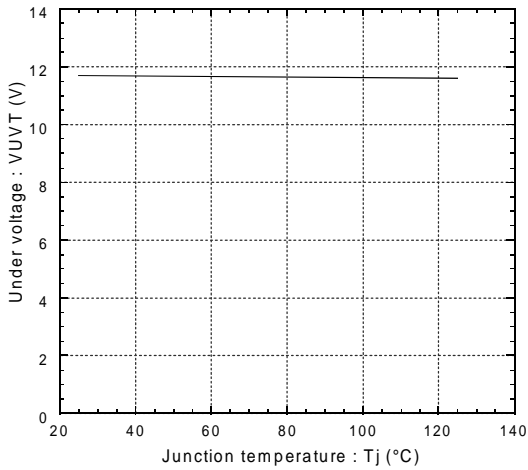
Power supply current vs. Switching frequency
Tj=100°C



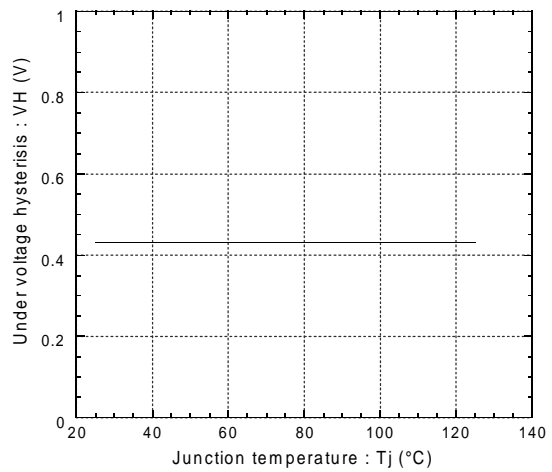
Input signal threshold voltage vs. Power supply voltage
Tj=25°C (solid line), Tj=125°C (dashed line)



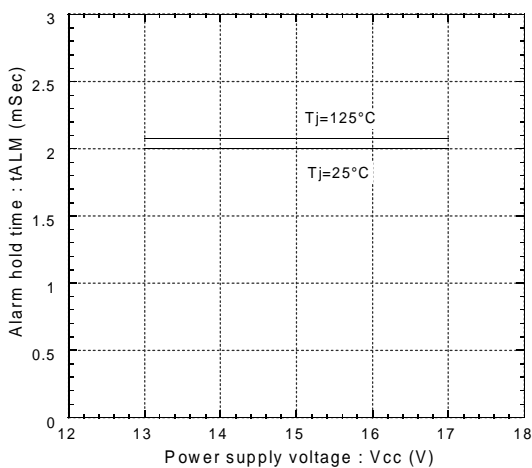
Under voltage vs. Junction temperature



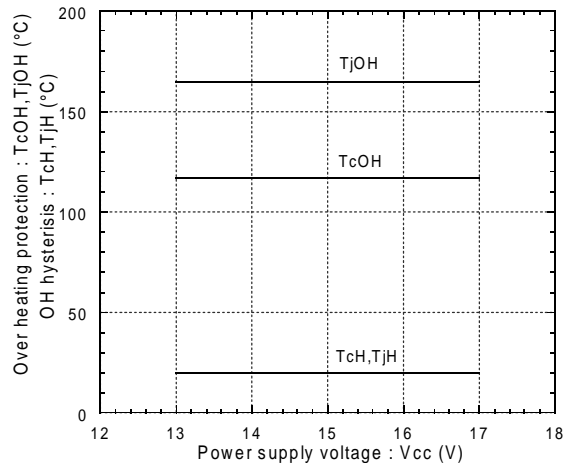
Under voltage hysteresis vs. Junction temperature



Alarm hold time vs. Power supply voltage

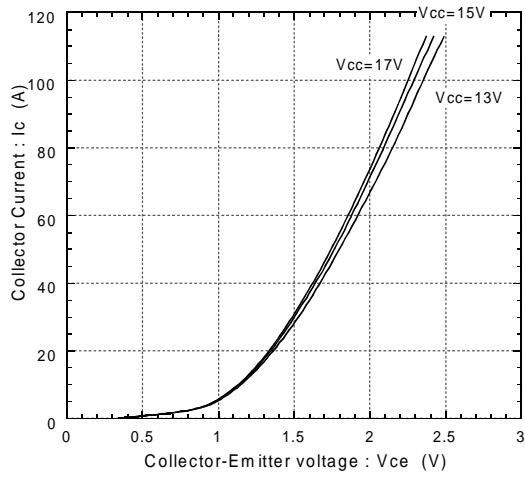


Over heating characteristics
TcOH, TjOH, TcH, TjH vs. Vcc

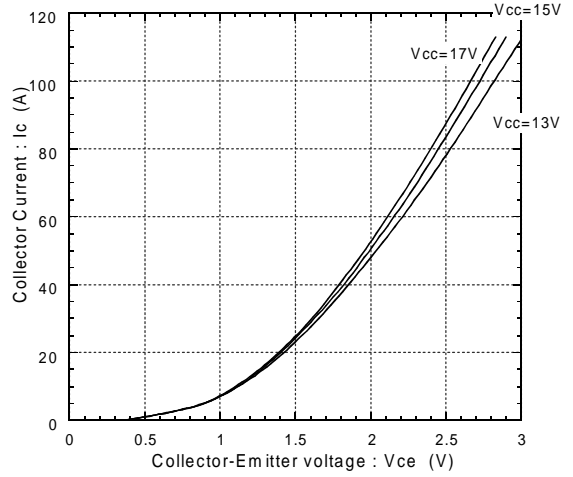


● Inverter

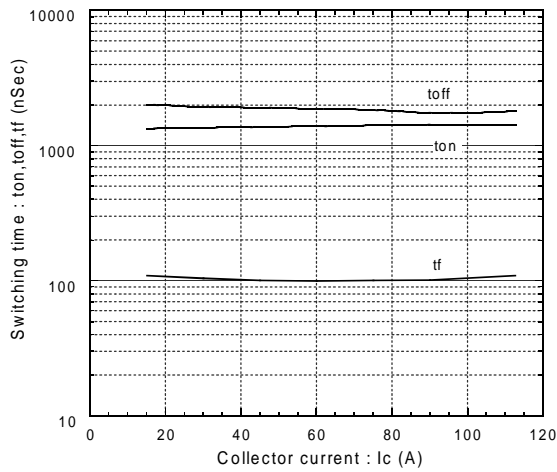
Collector current vs. Collector-Emittter voltage
T_j=25°C



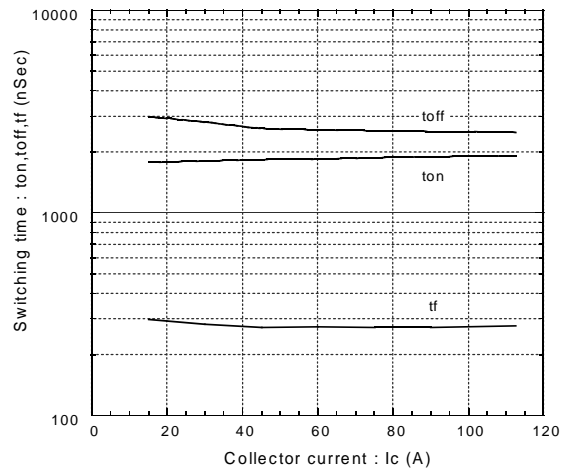
Collector current vs. Collector-Emittter voltage
T_j=125°C



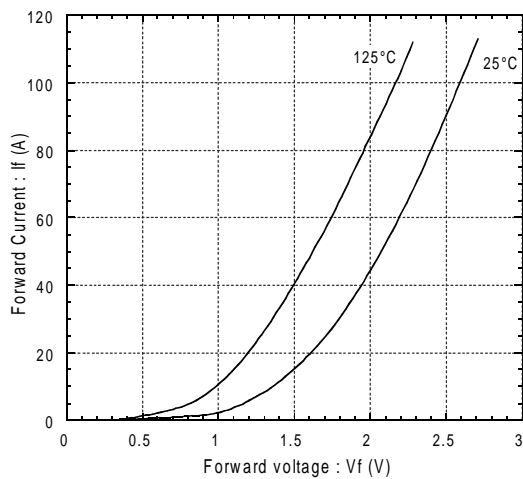
Switching time vs. Collector current
E_{dc}=600V, V_{cc}=15V, T_j=25°C



Switching time vs. Collector current
E_{dc}=600V, V_{cc}=15V, T_j=125°C



Forward current vs. Forward voltage



Reverse recovery characteristics
trr, lrr vs. IF

